



Phase Control Thyristors (Hockey PUK Version), 410 A



A-PUK (TO-200AB)

FEATURES

- Center amplifying gate
- Metal case with ceramic insulator
- International standard case A-PUK (TO-200AB)
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

RoHS
COMPLIANT

TYPICAL APPLICATIONS

- DC motor controls
- Controlled DC power supplies
- AC controllers

PRIMARY CHARACTERISTICS

| | |
|-----------------------|---|
| $I_{T(AV)}$ | 410 A |
| V_{DRM}/V_{RRM} | 400 V, 800 V, 1200 V, 1400 V, 1600 V, 1800 V, 2000 V |
| V_{TM} | 1.69 V |
| I_{GT} | 90 mA |
| T_J | -40 °C to +125 °C |
| Package | A-PUK (TO-200AB) |
| Circuit configuration | Single SCR |

MAJOR RATINGS AND CHARACTERISTICS

| PARAMETER | TEST CONDITIONS | VALUES | UNITS |
|-------------------|-----------------|-------------|-------------------|
| $I_{T(AV)}$ | | 410 | A |
| | T_{hs} | 55 | °C |
| $I_{T(RMS)}$ | | 780 | A |
| | T_{hs} | 25 | °C |
| I_{TSM} | 50 Hz | 5700 | A |
| | 60 Hz | 5970 | |
| I^2t | 50 Hz | 163 | kA ² s |
| | 60 Hz | 149 | |
| V_{DRM}/V_{RRM} | | 400 to 2000 | V |
| t_q | Typical | 100 | μs |
| T_J | | -40 to +125 | °C |

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS

| TYPE NUMBER | VOLTAGE CODE | V_{DRM}/V_{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V | V_{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V | I_{DRM}/I_{RRM} , MAXIMUM AT $T_J = T_J$ MAXIMUM mA |
|--------------|--------------|--|---|---|
| VS-ST230C..C | 04 | 400 | 500 | 30 |
| | 08 | 800 | 900 | |
| | 12 | 1200 | 1300 | |
| | 14 | 1400 | 1500 | |
| | 16 | 1600 | 1700 | |
| | 18 | 1800 | 1900 | |
| | 20 | 2000 | 2100 | |

**ABSOLUTE MAXIMUM RATINGS**

| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
|--|---------------|---|---|----------------|
| Maximum average on-state current at heatsink temperature | $I_{T(AV)}$ | 180° conduction, half sine wave double side (single side) cooled | 410 (165) | A |
| | | | 55 (85) | °C |
| Maximum RMS on-state current | $I_{T(RMS)}$ | DC at 25 °C heatsink temperature double side cooled | 780 | |
| Maximum peak, one-cycle non-repetitive surge current | I_{TSM} | <div> <div> $t = 10 \text{ ms}$ $t = 8.3 \text{ ms}$ </div> <div> No voltage reappplied 100 % V_{RRM} reappplied </div> </div> | <div> 5700 5970 4800 5000 </div> | A |
| | | Sinusoidal half wave, initial $T_J = T_J$ maximum | | |
| Maximum I^2t for fusing | I^2t | <div> $t = 10 \text{ ms}$ $t = 8.3 \text{ ms}$ </div> <div> No voltage reappplied 100 % V_{RRM} reappplied </div> | <div> 163 148 115 105 </div> | kA^2s |
| Maximum $I^2\sqrt{t}$ for fusing | $I^2\sqrt{t}$ | $t = 0.1$ to 10 ms , no voltage reappplied | 1630 | $kA^2\sqrt{s}$ |
| Low level value of threshold voltage | $V_{T(TO)1}$ | $(16.7 \% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$, $T_J = T_J$ maximum | 0.92 | V |
| High level value of threshold voltage | $V_{T(TO)2}$ | $(I > \pi \times I_{T(AV)})$, $T_J = T_J$ maximum | 0.98 | |
| Low level value of on-state slope resistance | r_{t1} | $(16.7 \% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$, $T_J = T_J$ maximum | 0.88 | $m\Omega$ |
| High level value of on-state slope resistance | r_{t2} | $(I > \pi \times I_{T(AV)})$, $T_J = T_J$ maximum | 0.81 | |
| Maximum on-state voltage | V_{TM} | $I_{pk} = 880 \text{ A}$, $T_J = T_J$ maximum, $t_p = 10 \text{ ms}$ sine pulse | 1.69 | V |
| Maximum holding current | I_H | $T_J = 25 \text{ °C}$, anode supply 12 V resistive load | 600 | mA |
| Maximum (typical) latching current | I_L | | 1000 (300) | |

SWITCHING

| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
|--|---------|---|--------|------------|
| Maximum non-repetitive rate of rise of turned-on current | di/dt | Gate drive 20 V, 20 Ω , $t_r \leq 1 \mu s$ $T_J = T_J$ maximum, anode voltage $\leq 80 \% V_{DRM}$ | 1000 | A/ μs |
| Typical delay time | t_d | Gate current 1 A, $di_g/dt = 1 \text{ A}/\mu s$ $V_d = 0.67 \% V_{DRM}$, $T_J = 25 \text{ °C}$ | 1.0 | μs |
| Typical turn-off time | t_q | $I_{TM} = 300 \text{ A}$, $T_J = T_J$ maximum, $di/dt = 20 \text{ A}/\mu s$, $V_R = 50 \text{ V}$, $dV/dt = 20 \text{ V}/\mu s$, gate 0 V 100 Ω , $t_p = 500 \mu s$ | 100 | |

BLOCKING

| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
|--|--------------------------|--|--------|------------|
| Maximum critical rate of rise of off-state voltage | dV/dt | $T_J = T_J$ maximum linear to 80 % rated V_{DRM} | 500 | V/ μs |
| Maximum peak reverse and off-state leakage current | I_{RRM} , I_{DRM} | $T_J = T_J$ maximum, rated V_{DRM}/V_{RRM} applied | 30 | mA |

**TRIGGERING**

| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | | UNITS |
|-------------------------------------|-------------|--|--------|------|-------|
| | | | TYP. | MAX. | |
| Maximum peak gate power | P_{GM} | $T_J = T_J$ maximum, $t_p \leq 5$ ms | 10.0 | | W |
| Maximum average gate power | $P_{G(AV)}$ | $T_J = T_J$ maximum, $f = 50$ Hz, $d\% = 50$ | 2.0 | | |
| Maximum peak positive gate current | I_{GM} | $T_J = T_J$ maximum, $t_p \leq 5$ ms | 3.0 | | A |
| Maximum peak positive gate voltage | $+V_{GM}$ | $T_J = T_J$ maximum, $t_p \leq 5$ ms | 20 | | V |
| Maximum peak negative gate voltage | $-V_{GM}$ | | 5.0 | | |
| DC gate current required to trigger | I_{GT} | $T_J = -40$ °C | 180 | - | mA |
| | | $T_J = 25$ °C | 90 | 150 | |
| | | $T_J = 125$ °C | 40 | - | |
| DC gate voltage required to trigger | V_{GT} | $T_J = -40$ °C | 2.9 | - | V |
| | | $T_J = 25$ °C | 1.8 | 3.0 | |
| | | $T_J = 125$ °C | 1.2 | - | |
| DC gate current not to trigger | I_{GD} | $T_J = T_J$ maximum | 10 | | mA |
| DC gate voltage not to trigger | V_{GD} | | 0.25 | | V |

THERMAL AND MECHANICAL SPECIFICATIONS

| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
|--|--------------|---|------------------|-----------|
| Maximum operating temperature range | T_J | | -40 to 125 | °C |
| Maximum storage temperature range | T_{Stg} | | -40 to 150 | |
| Maximum thermal resistance, junction to heatsink | R_{thJ-hs} | DC operation single side cooled | 0.17 | K/W |
| | | DC operation double side cooled | 0.08 | |
| Maximum thermal resistance, case to heatsink | R_{thC-hs} | DC operation single side cooled | 0.033 | |
| | | DC operation double side cooled | 0.017 | |
| Mounting force, ± 10 % | | | 4900 (500) | N (kg) |
| Approximate weight | | | 50 | g |
| Case style | | See dimensions - link at the end of datasheet | A-PUK (TO-200AB) | |

 ΔR_{thJC} CONDUCTION

| CONDUCTION ANGLE | SINUSOIDAL CONDUCTION | | RECTANGULAR CONDUCTION | | TEST CONDITIONS | UNITS |
|------------------|-----------------------|-------------|------------------------|-------------|---------------------|-------|
| | SINGLE SIDE | DOUBLE SIDE | SINGLE SIDE | DOUBLE SIDE | | |
| 180° | 0.015 | 0.017 | 0.011 | 0.011 | $T_J = T_J$ maximum | K/W |
| 120° | 0.018 | 0.019 | 0.019 | 0.019 | | |
| 90° | 0.024 | 0.024 | 0.026 | 0.026 | | |
| 60° | 0.035 | 0.035 | 0.036 | 0.036 | | |
| 30° | 0.060 | 0.060 | 0.060 | 0.061 | | |

Note

- The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

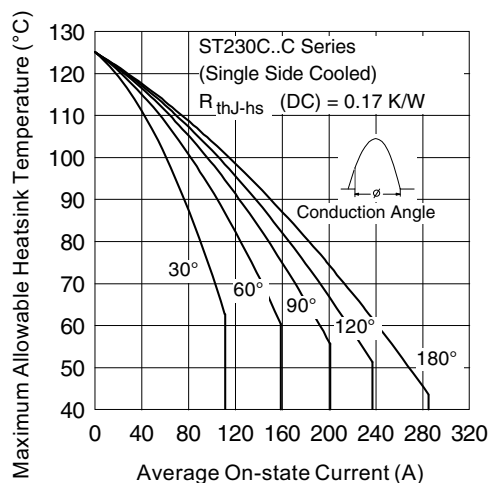


Fig. 1 - Current Ratings Characteristics

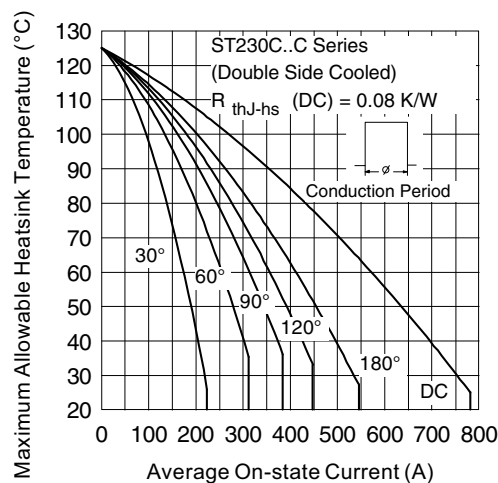


Fig. 4 - Current Ratings Characteristics

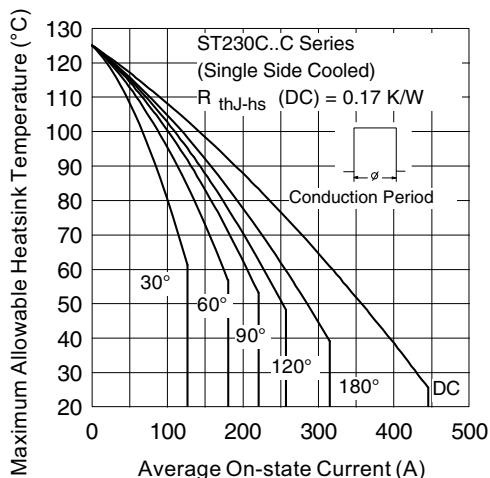


Fig. 2 - Current Ratings Characteristics

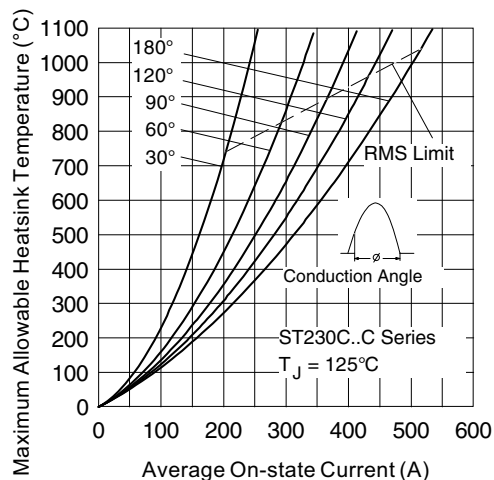


Fig. 5 - On-State Power Loss Characteristics

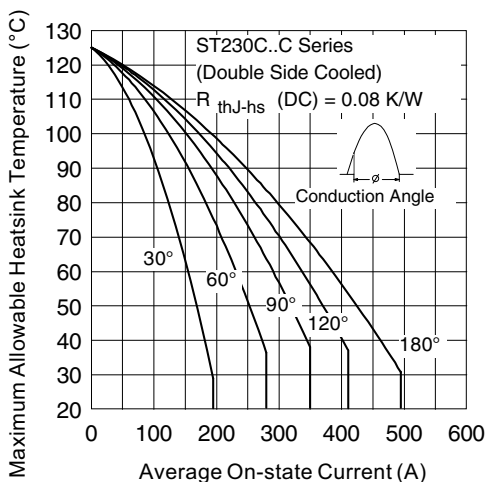


Fig. 3 - Current Ratings Characteristics

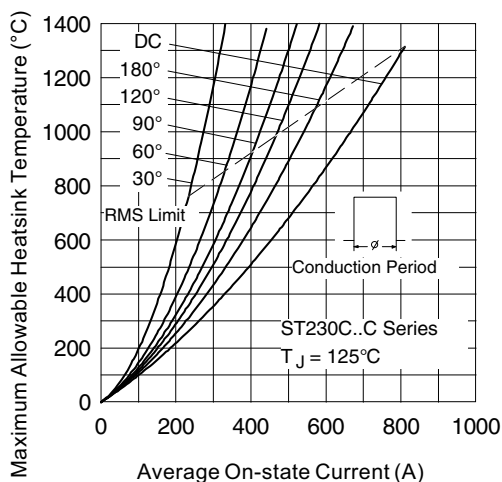


Fig. 6 - On-State Power Loss Characteristics

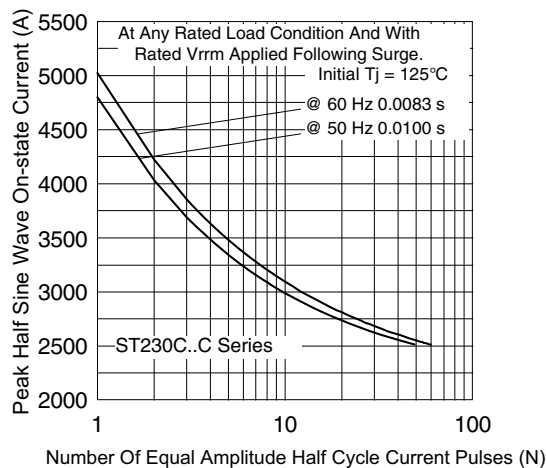


Fig. 7 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

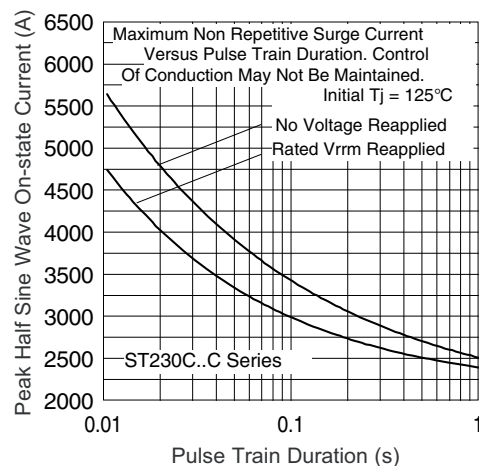


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

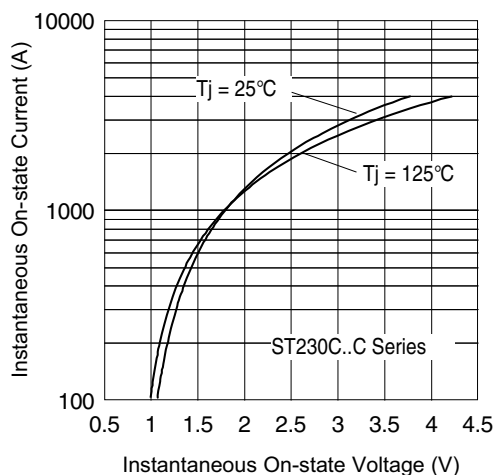
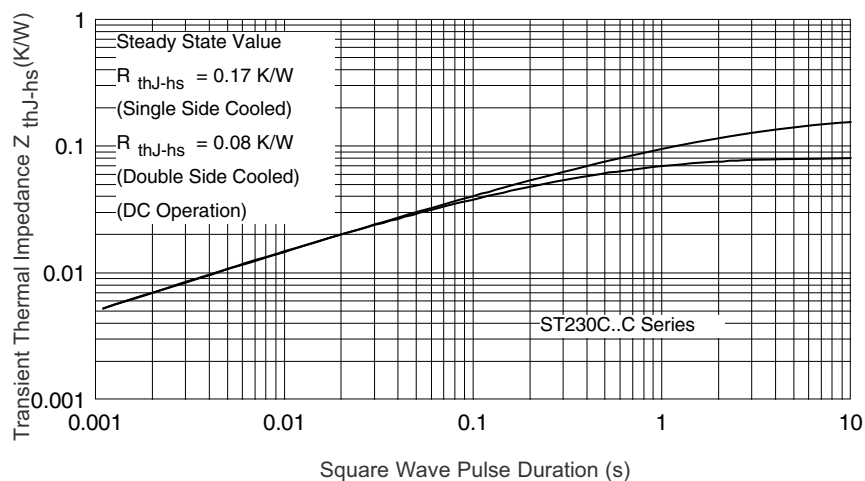


Fig. 9 - On-State Voltage Drop Characteristics

Fig. 10 - Thermal Impedance Z_{thJ-hs} Characteristics

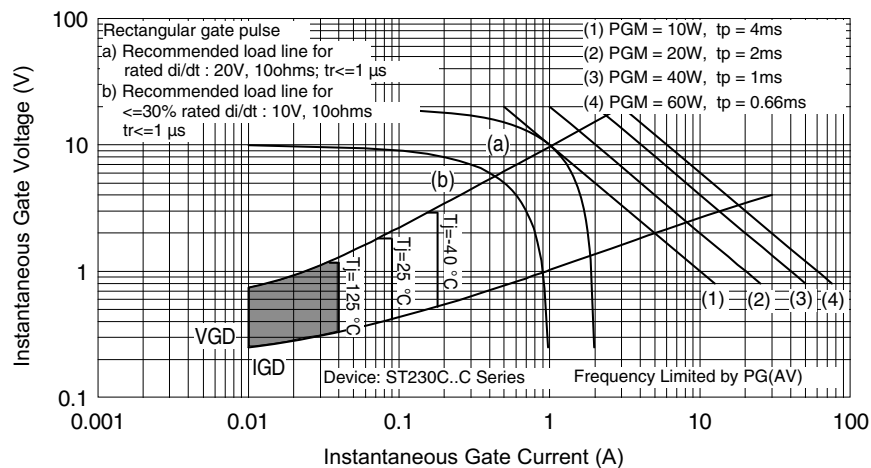


Fig. 11 - Gate Characteristics

ORDERING INFORMATION TABLE

| Device code | VS- | ST | 23 | 0 | C | 20 | C | 1 | - |
|-------------|-----|-----|-----|-----|-----|-----|-----|-----|-----|
| | (1) | (2) | (3) | (4) | (5) | (6) | (7) | (8) | (9) |

- 1** - Vishay Semiconductors product
- 2** - Thyristor
- 3** - Essential part number
- 4** - 0 = converter grade
- 5** - C = ceramic PUK
- 6** - Voltage code x 100 = V_{RRM} (see Voltage Ratings table)
- 7** - C = PUK case A-PUK (TO-200AB)
- 8** - 0 = eyelet terminals (gate and auxiliary cathode unsoldered leads)
1 = fast-on terminals (gate and auxiliary cathode unsoldered leads)
2 = eyelet terminals (gate and auxiliary cathode soldered leads)
3 = fast-on terminals (gate and auxiliary cathode soldered leads)
- 9** - Critical dV/dt: • None = 500 V/μs (standard selection)
• L = 1000 V/μs (special selection)

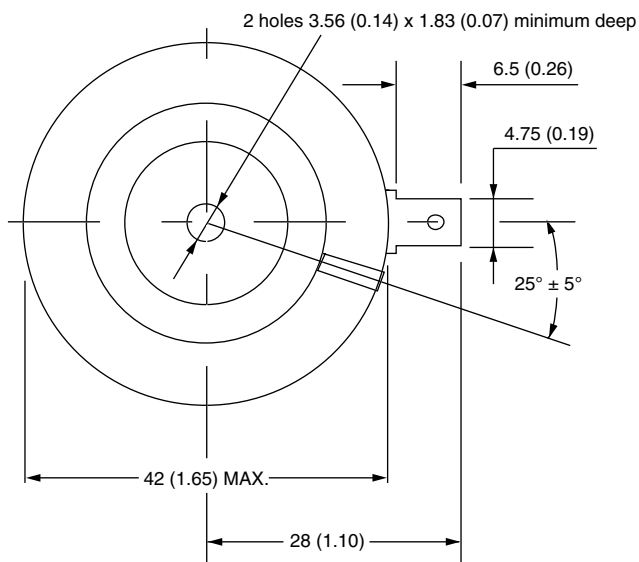
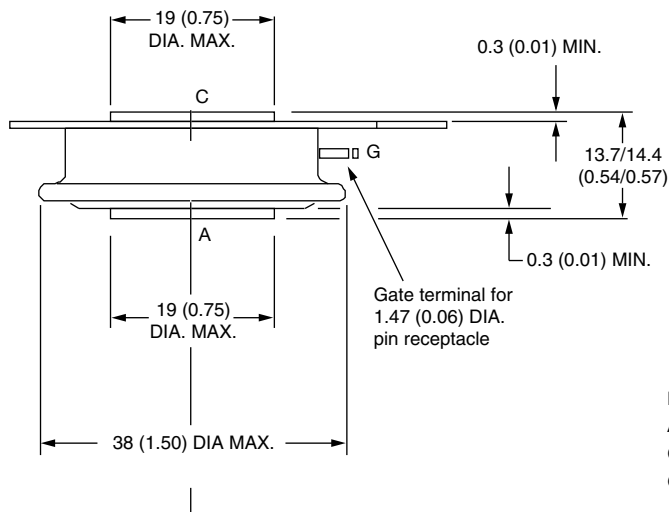
LINKS TO RELATED DOCUMENTS

| | |
|------------|--|
| Dimensions | www.vishay.com/doc?95074 |
|------------|--|

A-PUK (TO-200AB)

DIMENSIONS in millimeters (inches)

Anode to gate
Creepage distance: 7.62 (0.30) minimum
Strike distance: 7.12 (0.28) minimum



Quote between upper and lower pole pieces has to be considered after application of mounting force (see thermal and mechanical specification)



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